

April 1995

8A, 400V - 600V Ultrafast Dual Diodes

Features

- Ultrafast with Soft Recovery <60ns
- Operating Temperature +175°C
- Reverse Voltage Up To 600V
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Description

The RURP840CC, RURP850CC, and RURP860CC are ultrafast dual diodes with soft recovery characteristics ($t_{RR} < 60\text{ns}$). They have low forward voltage drop and are silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

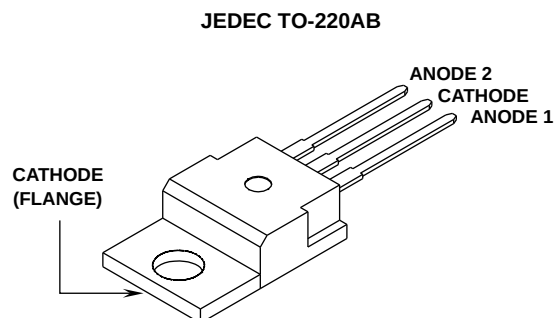
PACKAGING AVAILABILITY

PART NUMBER	PACKAGE	BRAND
RURP840CC	TO-220AB	RURP840C
RURP850CC	TO-220AB	RURP850C
RURP860CC	TO-220AB	RURP860C

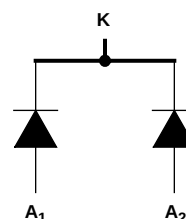
NOTE: When ordering, use the entire part number.

Formerly developmental type TA09616.

Package



Symbol



Absolute Maximum Ratings (per leg) $T_C = +25^\circ\text{C}$, Unless Otherwise Specified

	RURP840CC	RURP850CC	RURP860CC	UNITS
Peak Repetitive Reverse Voltage V_{RRM}	400	500	600	V
Working Peak Reverse Voltage V_{RWM}	400	500	600	V
DC Blocking Voltage V_R	400	500	600	V
Average Rectified Forward Current $I_{F(AV)}$ ($T_C = +155^\circ\text{C}$)	8	8	8	A
Repetitive Peak Surge Current I_{FSM} (Square Wave, 20kHz)	16	16	16	A
Nonrepetitive Peak Surge Current I_{FSM} (Halfwave, 1 phase, 60Hz)	100	100	100	A
Maximum Power Dissipation P_D	75	75	75	W
Avalanche Energy (See Figures 10 and 11). E_{AVL}	20	20	20	mJ
Operating and Storage Temperature T_{STG}, T_J	-65 to +175	-65 to +175	-65 to +175	°C

Specifications RURP840CC, RURP850CC, RURP860CC

Electrical Specifications (per leg) $T_C = +25^\circ\text{C}$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	LIMITS									UNITS
		RURP840CC			RURP850CC			RURP860CC			
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V _F	I _F = 8A, T _C = +25°C	-	-	1.3	-	-	1.5	-	-	1.5	V
	I _F = 8A, T _C = +150°C	-	-	1.0	-	-	1.2	-	-	1.2	V
I _R	V _R = 400V, T _C = +25°C	-	-	100	-	-	-	-	-	-	μA
	V _R = 500V, T _C = +25°C	-	-	-	-	-	100	-	-	-	μA
	V _R = 600V, T _C = +25°C	-	-	-	-	-	-	-	-	100	μA
I _R	V _R = 400V, T _C = +150°C	-	-	500	-	-	-	-	-	-	μA
	V _R = 500V, T _C = +150°C	-	-	-	-	-	500	-	-	-	μA
	V _R = 600V, T _C = +150°C	-	-	-	-	-	-	-	-	500	μA
t _{RR}	I _F = 1A, dI _F /dt = 200A/μs	-	-	60	-	-	60	-	-	60	ns
	I _F = 8A, dI _F /dt = 200A/μs	-	-	70	-	-	70	-	-	70	ns
t _A	I _F = 8A, dI _F /dt = 200A/μs	-	32	-	-	32	-	-	32	-	ns
t _B	I _F = 8A, dI _F /dt = 200A/μs	-	21	-	-	21	-	-	21	-	ns
Q _{RR}	I _F = 8A, dI _F /dt = 200A/μs	-	195	-	-	195	-	-	195	-	nC
C _J	V _R = 10V, I _F = 0A	-	25	-	-	25	-	-	25	-	pF
R _{θJC}		-	-	2	-	-	2	-	-	2	°C/W

DEFINITIONS

V_F = Instantaneous forward voltage (pw = 300 μs , D = 2%).

I_R = Instantaneous reverse current.

t_{RR} = Reverse recovery time (See Figure 2), summation of $t_A + t_B$.

t_A = Time to reach peak reverse current (See Figure 2).

t_B = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 2).

Q_{RR} = Reverse recovery charge.

C_J = Junction Capacitance.

$R_{\theta JC}$ = Thermal resistance junction to case.

E_{AVL} = Controlled avalanche energy. (See Figures 10 and 11).

pw = pulse width.

D = duty cycle.

V_1 AMPLITUDE CONTROLS I_F
 V_2 AMPLITUDE CONTROLS dl_F/dt
 L_1 = SELF INDUCTANCE OF
 $R_4 + L_{\text{LOOP}}$

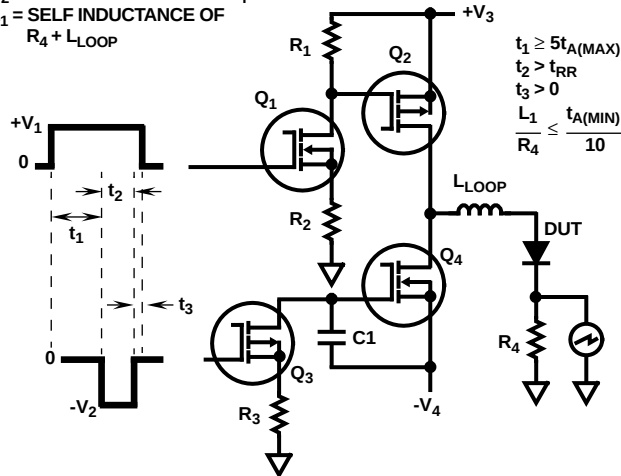


FIGURE 1. t_{RR} TEST CIRCUIT

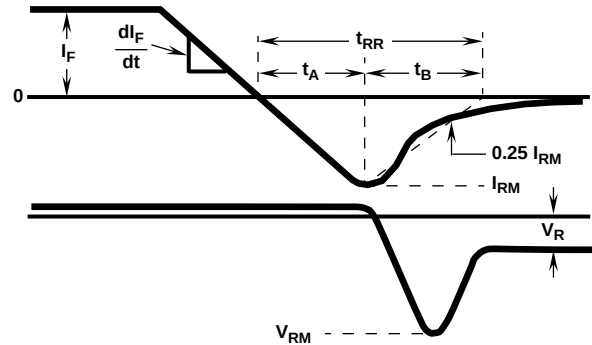


FIGURE 2. t_{RR} WAVEFORMS AND DEFINITIONS

Typical Performance Curves

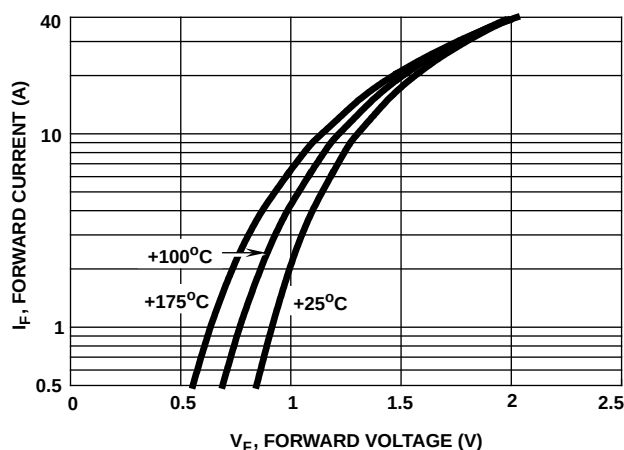


FIGURE 3. TYPICAL FORWARD CURRENT vs FORWARD VOLTAGE DROP

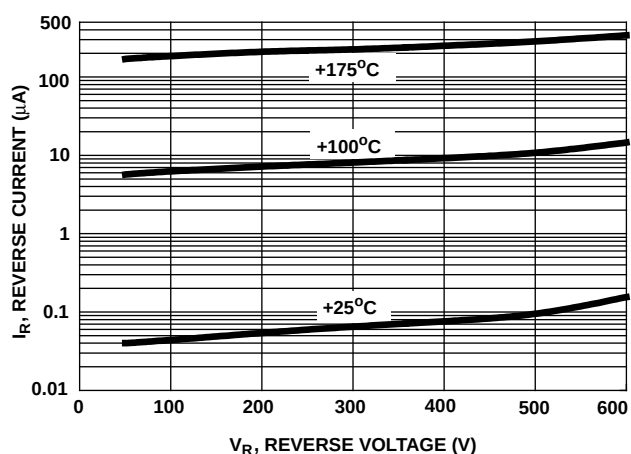


FIGURE 4. TYPICAL REVERSE CURRENT vs REVERSE VOLTAGE

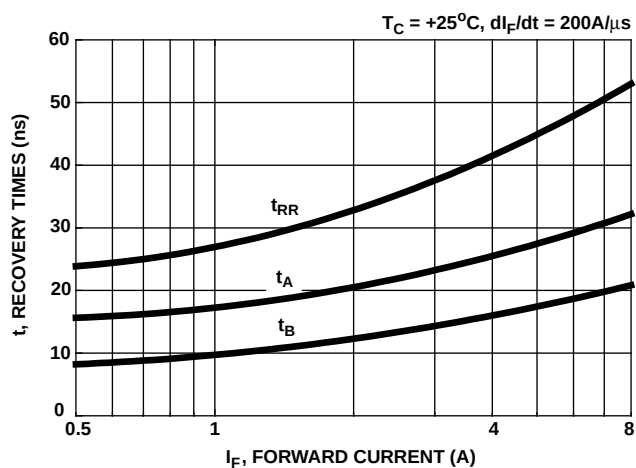


FIGURE 5. TYPICAL t_{RR} , t_A AND t_B CURVES vs FORWARD CURRENT AT +25°C

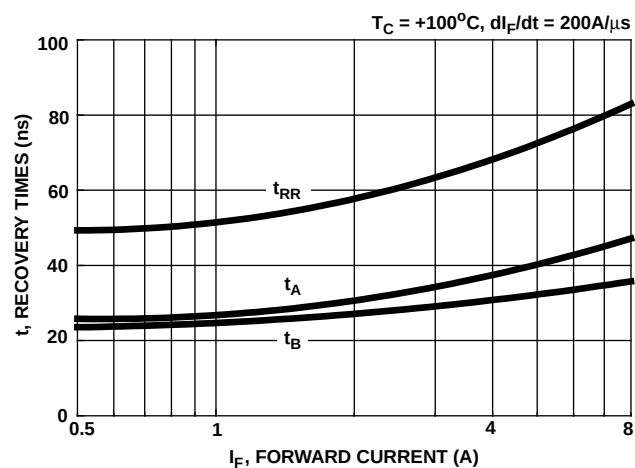


FIGURE 6. TYPICAL t_{RR} , t_A AND t_B CURVES vs FORWARD CURRENT AT +100°C

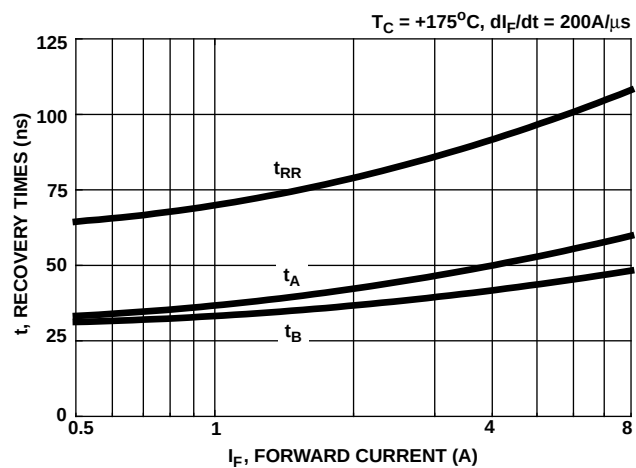


FIGURE 7. TYPICAL t_{RR} , t_A AND t_B CURVES vs FORWARD CURRENT AT +175°C

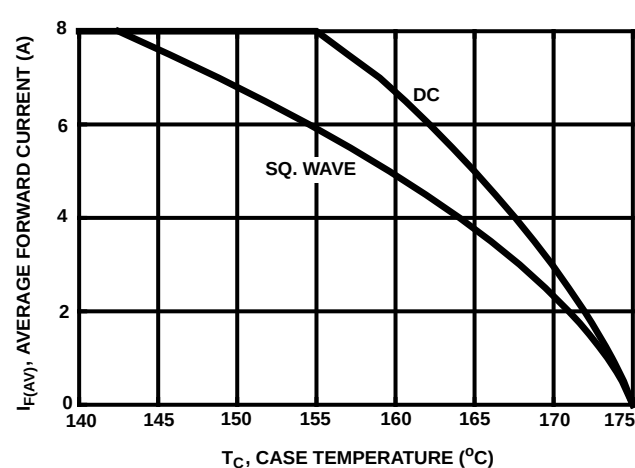


FIGURE 8. CURRENT DERATING CURVE FOR ALL TYPES

Typical Performance Curves (Continued)

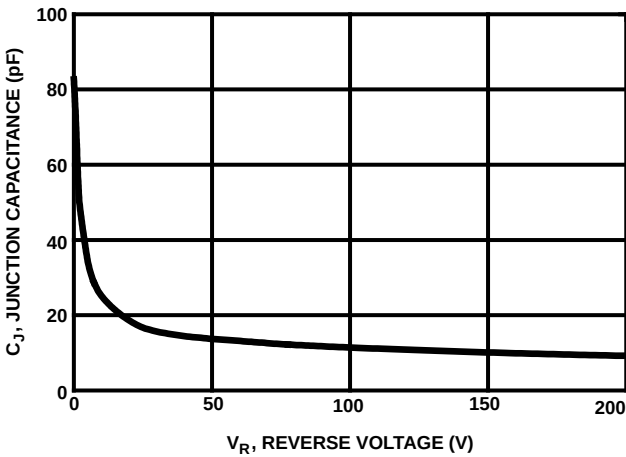


FIGURE 9. TYPICAL JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuit and Waveforms

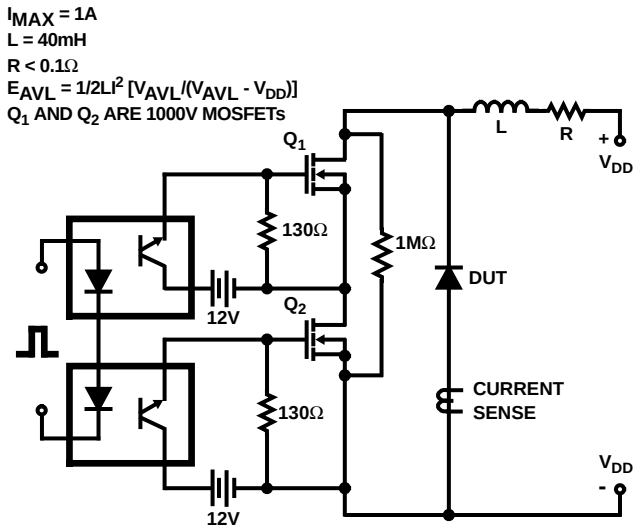


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

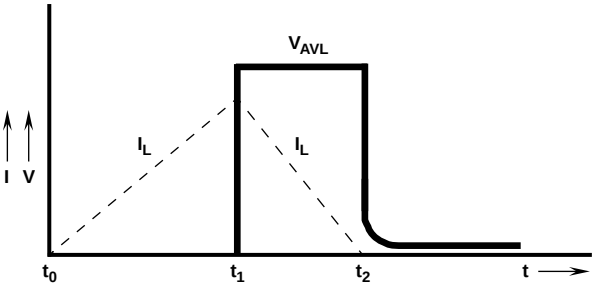


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS